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### 10 + 10W STEREO AMPLIFIER WITH MUTE & ST-BY

- WIDE SUPPLY VOLTAGE RANGE UP TO ±20V
- SPLIT SUPPLY
- HIGH OUTPUT POWER 10 + 10W @ THD = 10%,  $R_L = 8\Omega$ ,  $V_S = \pm 14V$
- NO POP AT TURN-ON/OFF
- MUTE (POP FREE)
- STAND-BY FEATURE (LOW I<sub>q</sub>)
- THERMAL OVERLOAD PROTECTION
- SHORT CIRCUIT PROTECTION TO GND

#### **DESCRIPTION**

The TDA7269 is class AB dual Audio power amplifier assembled in the Multiwatt package, specially designed for high quality sound application as Hi-Fi music centers and stereo TV sets.

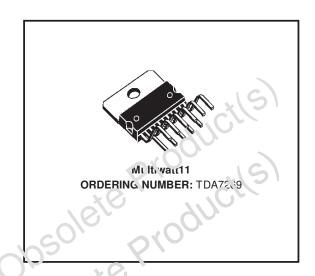
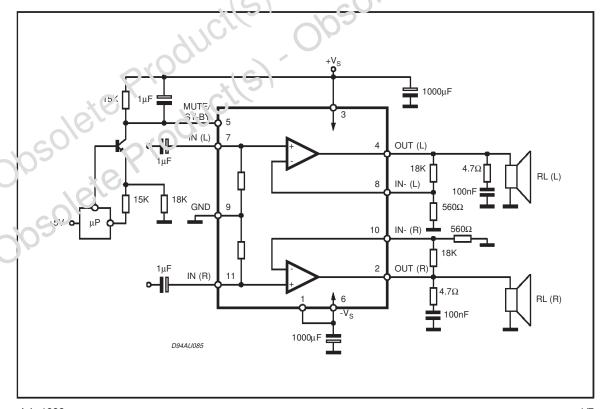


Figure 1: Typical Application Circuit

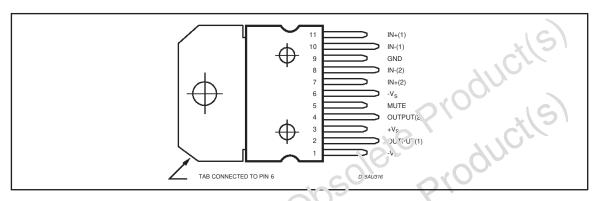


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#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	DC Supply Voltage	±22	V
Io	Output Peak Current (internally limited)	3	Α
P <sub>tot</sub>	Power Dissipation T <sub>case</sub> = 70°C	40	W
T <sub>op</sub>	Operating Temperature	0 to 70	°C
T <sub>stg</sub> , T <sub>j</sub>	Storage and Junction Temperature	-40 to +150	°C

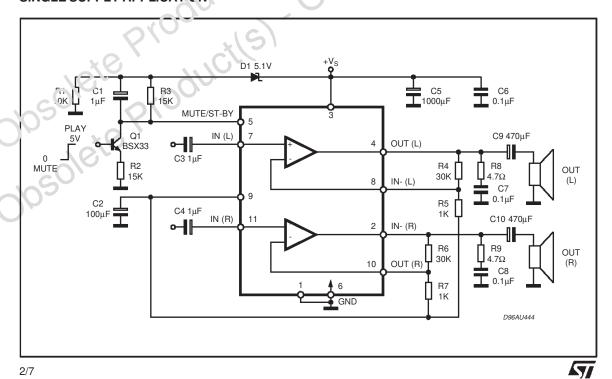
#### PIN CONNECTION (Top view)



#### THERMAL DATA

Symbol	Description				Unit
R <sub>th j-case</sub>	Thermal Resistance Junction-case	~0,	Max	2.8	°C/W

#### SINGLE SUPPLY APPLICATION



# **ELECTRICAL CHARACTERISTICS** (Refer to the test circuit, $V_S = \pm 14V$ ; $R_L = 8\Omega$ ; $R_S = 50\Omega$ ; $R_S = 50\Omega$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Range		<u>+</u> 5		<u>+</u> 20	V
Iq	Total Quiescent Current			60	100	mA
Vos	Input Offset Voltage		-25		+25	mV
I <sub>b</sub>	Non Inverting Input Bias Current			500		nA
Po	Output Power	$THD = 10\%$ $R_L = 8\Omega;$ $V_S \pm 12.5V; R_L = 4\Omega$	8 7.5	10 10		W W
		THD = 1% $R_L = 8Ω$ ; $V_S \pm 12.5V$ ; $R_L = 4Ω$		7.5 7.5		W V
THD	Total Harmonic Distortion	$R_L = 8\Omega$ ; $P_O = 1W$ ; $f = 1KHz$		0.03	Lie,	%
		$R_L = 8\Omega$ ; $P_O = 0.1$ to 5W; f = 100Hz to 15KHz		91,	0.7	%
		$R_L = 4\Omega$ ; $P_O = 1W$ ; $f = 1KHz$		ე.02	1	%
		$R_L = 4\Omega$ ; $V_S \pm 10V$ ; $P_O = 0.1$ to $5W$ ; f = 100Hz to $15KHz$		41	C	%
Ст	Cross Talk	f = 1KHz f = 10KHz	50	70 60		dB dB
SR	Slew Rate	200	6.5	10		V/μs
G <sub>OL</sub>	Open Loop Voltage Gain	()		80		dB
e <sub>N</sub>	Total Input Noise	A Curve \(\sigma = 20Hz \) to 22KHz		3 4	8	μV μV
Ri	Input Resistance		15	20		ΚΩ
SVR	Supply Voltage Rejection (each channel)	fr = 100Hz		60		dB
T <sub>j</sub>	Thermal Shut-dovn Junction Temperature	\		145		°C
MUTE FUN	CTION [1 of. +Vs] (*)					
VT <sub>MUTE</sub>	Mute / Play Threshold		-7	-6	-5	V
A <sub>M</sub>	Mune Attenuation		60	70		dB
STAND 6Y	rUNCTION [ref: +Vs] (Only for Sp	olit Supply)				
/L <sup>2</sup> I-RA	Stand-by / Mute Threshold		-3.5	-2.5	-1.5	V
A <sub>ST-BY</sub>	Stand-by Attenuation			110		dB
I <sub>q ST-BY</sub>	Quiescent Current @ Stand-by			3	6	mA

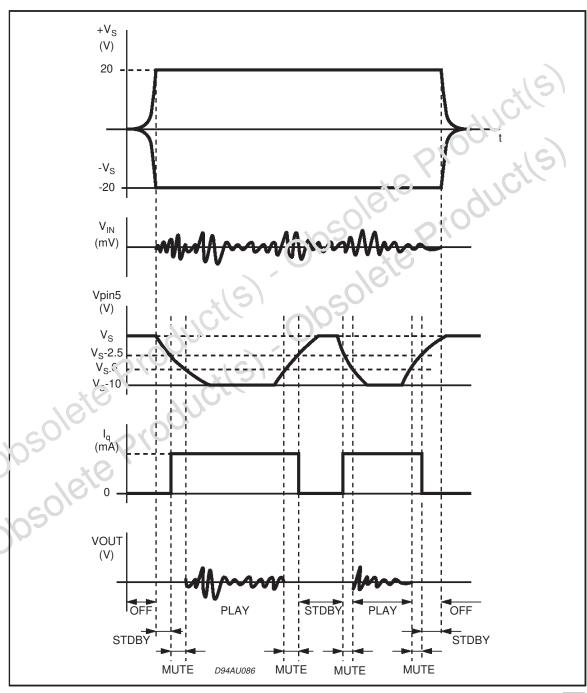
<sup>(\*)</sup> In mute condition the current drawn from Pin 5 must be  $\,\leq\!\!650\mu A.$ 

#### **MUTE STAND-BY FUNCTION**

The pin 5 (MUTE/STAND-BY) controls the amplifier status by two different thresholds, referred to  $+V_S$ .

- When  $V_{\text{pin}5}$  higher than = +Vs 2.5V the amplifier is in Stand-by mode and the final stage generators are off
- when V<sub>pin5</sub> is between +Vs 2.5V and +Vs
   6V the final stage current generators are switched on and the amplifier is in mute mode
- when V<sub>pin5</sub> is lower than +Vs 6V the amplifier is play mode.

Figure 2



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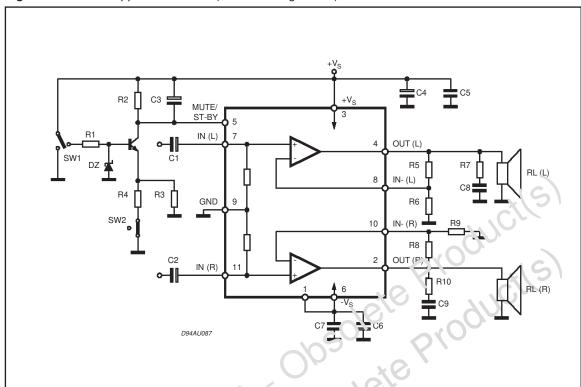


Figure 3: Test and Application Circuit (Stereo Configuration)

## APPLICATIONS SUGGESTION (Demo Board Schematic)

The recommended values of the external compo-

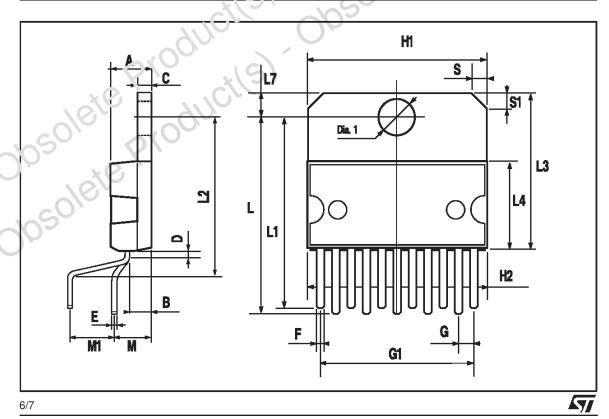
nents are those shown are the demo board schematic different values can be used: the following table can help the designer.

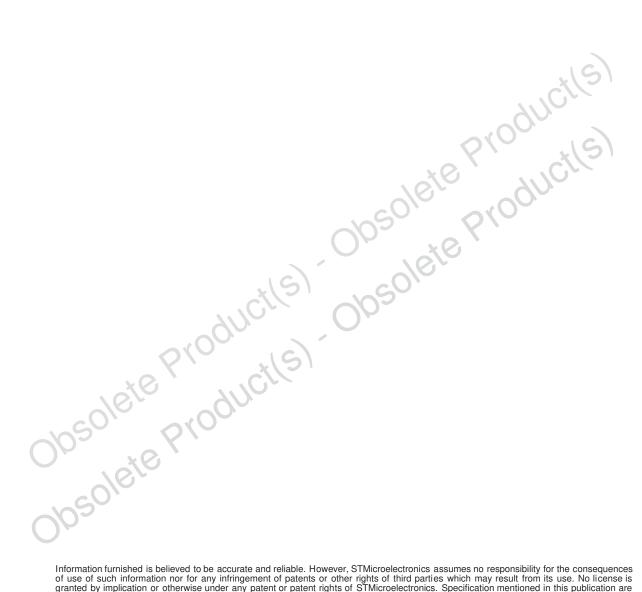
COMPONENTS RECOMMENDED VALUE		PURPOSE	LARGER THAN RECOMMENDED VALUE	SMALLER THAN RECOMMENDED VALUE	
R1 10KΩ Mu		Mute Circuit	Increase of Dz Biasing Current		
R2	15ΚΩ	Mute Circuit	V <sub>pin</sub> # 5 Shifted Downward	V <sub>pin</sub> # 5 Shifted Upward	
R3	18ΚΩ	Mute Circuit	V <sub>pin</sub> # 5 Shifted Upward	V <sub>pin</sub> # 5 Shifted Downward	
R/	15ΚΩ	Mute Circuit	V <sub>pin</sub> # 5 Shifted Upward	V <sub>pin</sub> # 5 Shifted Downward	
745, R8	λ̄5, R8 18KΩ		Increase of Gain		
R6, R9	560Ω	Setting (*)	Decrease of Gain		
R7, R10	4.7Ω	Frequency Stability	Danger of Oscillations	Danger of Oscillations	
C1, C2	1μF	Input DC Decoupling		Higher Low Frequency Cutoff	
C3	1μF	St-By/Mute Time Constant	Larger On/Off Time	Smaller On/Off Time	
C4, C6	1000μF	Supply Voltage Bypass		Danger of Oscillations	
C5, C7	0.1μF	Supply Voltage Bypass		Danger of Oscillations	
C8, C9	0.1μF	Frequency Stability			
Dz	5.1V	Mute Circuit			

<sup>(\*)</sup> Closed loop gain has to be => 25dB

#### **MULTIWATT11 PACKAGE MECHANICAL DATA**

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α			5			0.197	
В			2.65			0.104	
С			1.6			0.063	
D		1			0.039		
E	0.49		0.55	0.019		0.022	
F	0.88		0.95	0.035		0.037	
G	1.57	1.7	1.83	0.062	0.067	0.072	
G1	16.87	17	17.13	0.664	0.669	0 074	
H1	19.6			0.772		*(3)	
H2			20.2			0.795	
L	21.5		22.3	0.846	AV	0.878	
L1	21.4		22.2	0.843	~00.	0.874	
L2	17.4		18.1	0.685		0.713	
L3	17.25	17.5	17.75	0.679	0.689	0.699	
L4	10.3	10.7	10.9	0.403	0.421	0.429	
L7	2.65		2.9	0.154	~0,0	0.114	
М	4.1	4.3	4.5	0.161	0.169	0.177	
M1	4.88	5.08	5.3	0.192	0.200	0.209	
S	1.9		2.6	0.075	•	0.102	
S1	1.9		2.6	0.075		0.102	
Dia1	3.65	16	3.85	0.144		0.152	





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